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# 2SC4592

Silicon NPN Epitaxial

# HITACHI

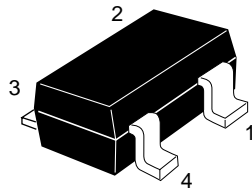
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## Application

UHF / VHF wide band amplifier

## Outline

MPAK-4



- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

## 2SC4592

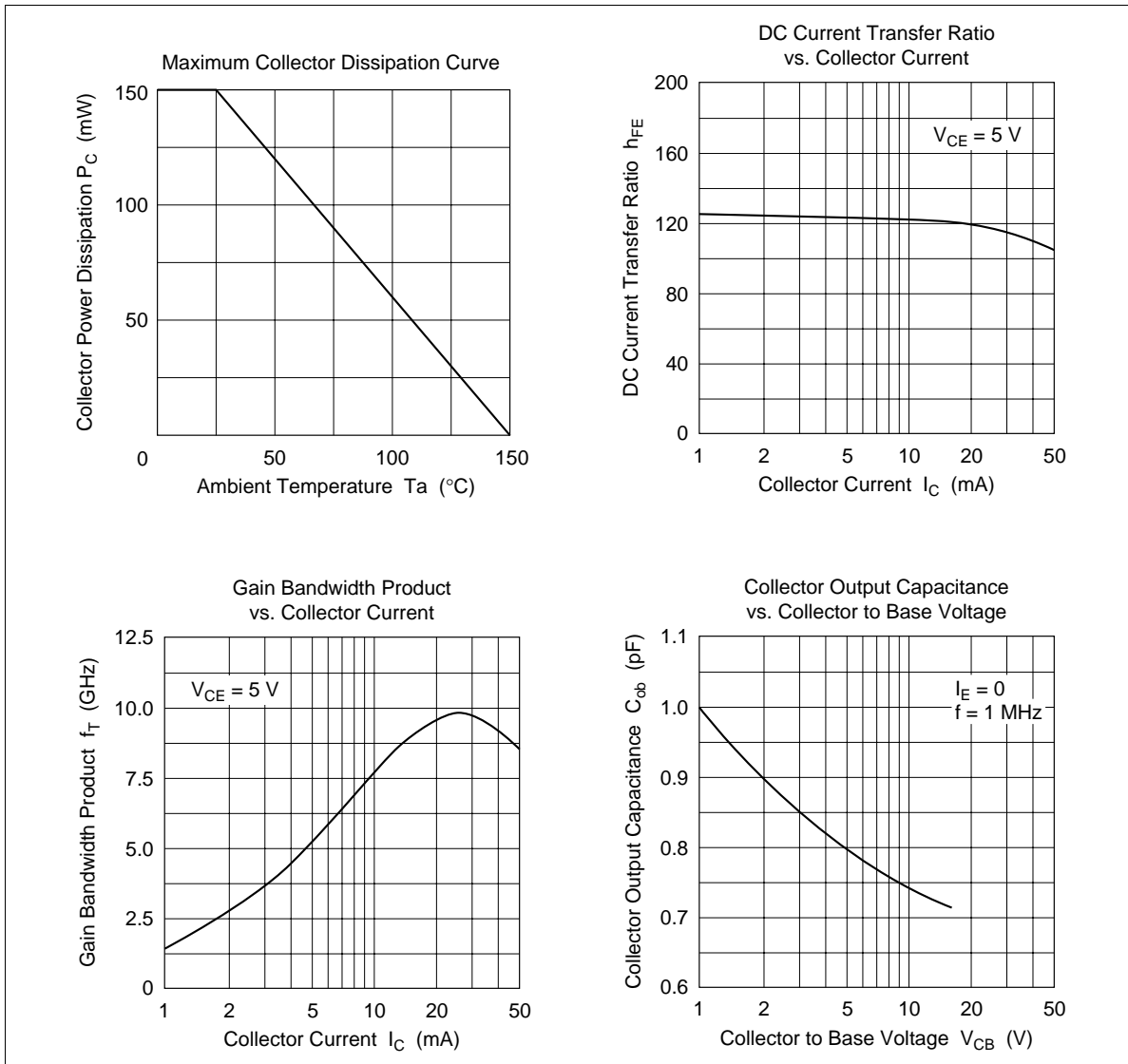
### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	15	V
Collector to emitter voltage	$V_{CEO}$	9	V
Emitter to base voltage	$V_{EBO}$	1.5	V
Collector current	$I_C$	50	mA
Collector power dissipation	$P_C$	150	mW
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

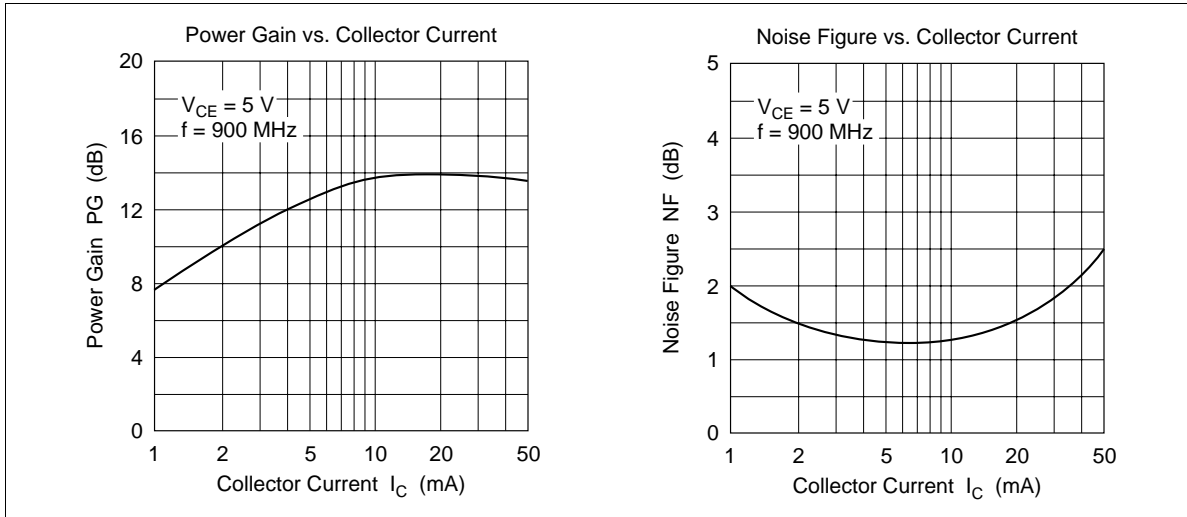
### Electrical Characteristics (Ta = 25°C)

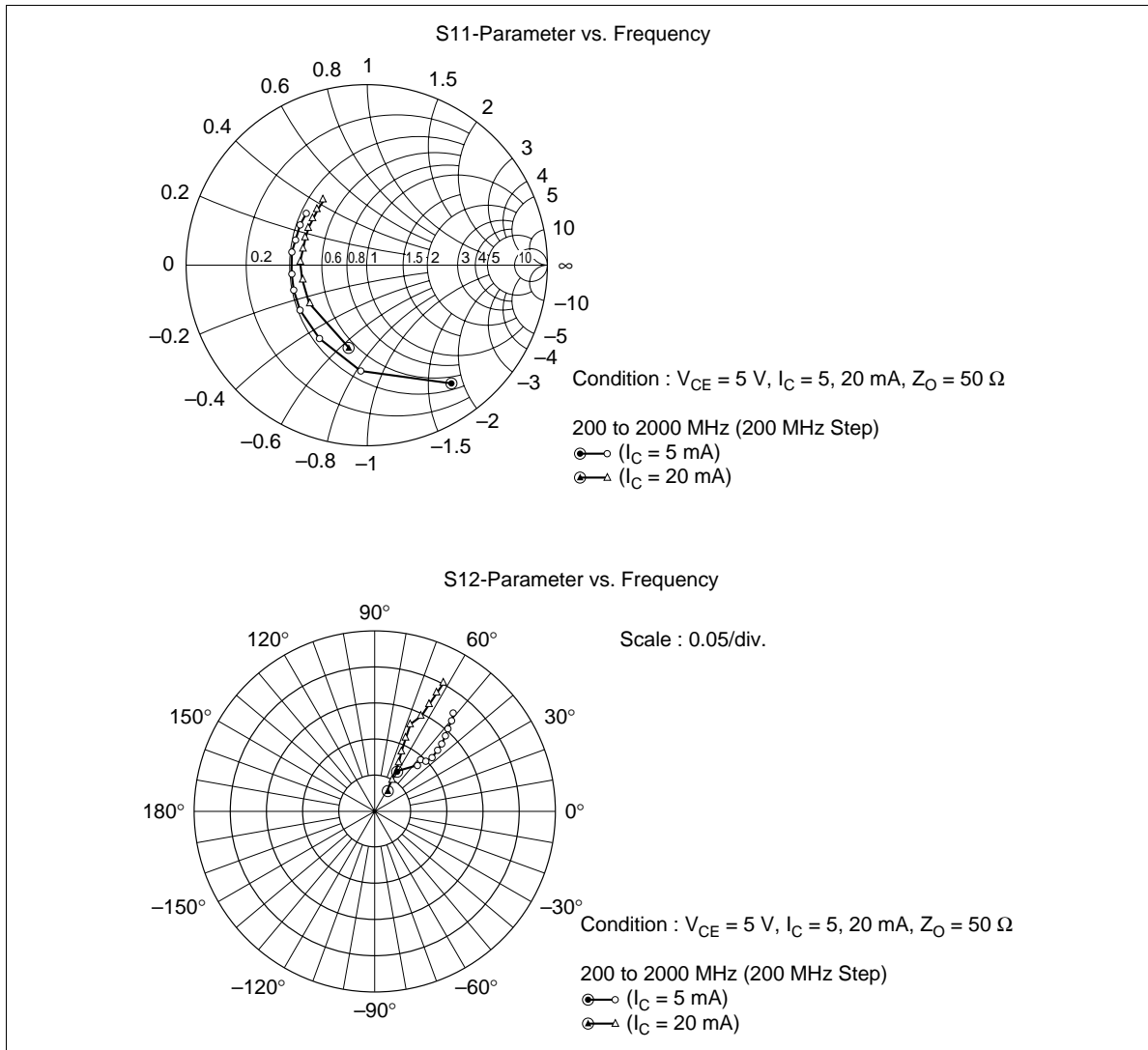
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector cutoff current	$I_{CBO}$	—	—	1	$\mu A$	$V_{CB} = 12 V, I_E = 0$
	$I_{CEO}$	—	—	1	mA	$V_{CE} = 9 V, R_{BE} = \infty$
Emitter cutoff current	$I_{EBO}$	—	—	10	$\mu A$	$V_{EB} = 1.5 V, I_C = 0$
DC current transfer ratio	$h_{FE}$	40	120	250		$V_{CE} = 5 V, I_C = 20 mA$
Collector output capacitance	$C_{ob}$	—	0.8	1.5	pF	$V_{CB} = 5 V, I_E = 0,$ $f = 1MHz$
Gain bandwidth product	$f_T$	7.0	9.5	—	GHz	$V_{CE} = 5 V, I_C = 20 mA$
Power gain	PG	11.0	14.0	—	dB	$V_{CE} = 5 V, I_C = 20 mA,$ $f = 900 MHz$
Noise figure	NF	—	1.2	2.5	dB	$V_{CE} = 5 V, I_C = 5 mA,$ $f = 900 MHz$

Note: Marking is "XN-".

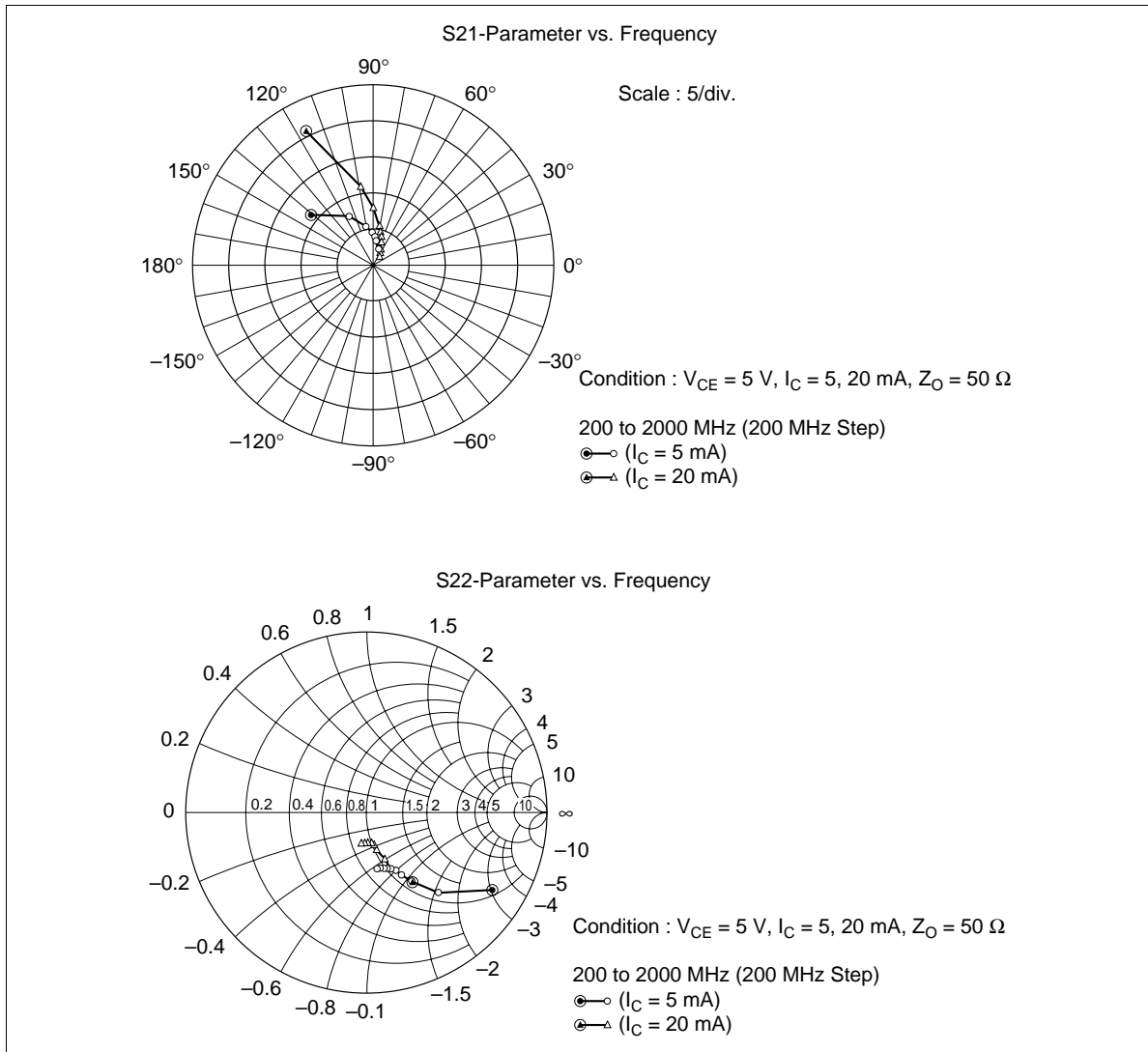


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**S Parameter** ( $V_{CE} = 5\text{ V}$ ,  $I_C = 5\text{ mA}$ ,  $Z_O = 50\ \Omega$ )

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
100	0.893	-28.8	12.428	159.3	0.034	74.2	0.939	-17.2
200	0.788	-54.8	10.823	141.1	0.058	61.4	0.819	-31.5
300	0.693	-76.3	9.118	127.1	0.076	52.8	0.699	-41.8
400	0.603	-94.1	7.714	116.9	0.087	47.9	0.602	-48.5
500	0.542	-110.1	6.565	108.8	0.094	45.3	0.531	-52.8
600	0.507	-122.6	5.693	102.5	0.100	44.0	0.478	-55.9
700	0.472	-133.8	5.002	96.9	0.105	43.2	0.437	-58.5
800	0.454	-144.1	4.477	92.3	0.110	42.8	0.405	-60.8
900	0.443	-152.1	4.001	88.2	0.115	43.3	0.382	-62.5
1000	0.436	-160.1	3.660	84.2	0.119	44.1	0.363	-64.3
1100	0.423	-167.8	3.372	80.9	0.124	44.6	0.350	-65.9
1200	0.420	-174.8	3.100	77.7	0.129	45.5	0.340	-66.8
1300	0.419	178.6	2.882	74.7	0.134	46.4	0.336	-68.2
1400	0.420	172.4	2.703	71.8	0.139	46.9	0.328	-69.9
1500	0.419	166.2	2.542	69.3	0.144	47.9	0.323	-71.3
1600	0.423	161.8	2.392	66.3	0.150	48.5	0.320	-72.0
1700	0.422	156.4	2.270	63.9	0.155	49.0	0.317	-74.2
1800	0.433	151.3	2.149	61.6	0.161	49.5	0.316	-76.0
1900	0.432	147.3	2.050	59.5	0.167	50.1	0.315	-77.4
2000	0.442	142.5	1.958	56.9	0.174	50.6	0.315	-79.0

**2SC4592****S Parameter** ( $V_{CE} = 5 \text{ V}$ ,  $I_C = 20 \text{ mA}$ ,  $Z_O = 50 \Omega$ )

Freq. (MHz)	S11		S21		S12		S22	
	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.	MAG.	ANG.
100	0.619	-64.2	31.361	137.5	0.025	63.5	0.729	-39.2
200	0.475	-104.2	20.515	116.0	0.036	56.8	0.483	-57.2
300	0.417	-128.3	14.505	105.1	0.045	57.8	0.356	-65.2
400	0.385	-145.2	11.189	98.3	0.054	60.1	0.287	-69.2
500	0.374	-157.4	9.053	93.4	0.063	61.6	0.245	-71.9
600	0.367	-166.9	7.608	89.6	0.072	62.8	0.220	-73.8
700	0.367	-175.4	6.547	86.1	0.081	64.1	0.201	-75.5
800	0.366	177.2	5.773	83.0	0.090	64.7	0.189	-77.2
900	0.369	172.0	5.121	80.6	0.100	64.9	0.181	-78.4
1000	0.368	166.2	4.632	77.9	0.109	65.1	0.175	-80.1
1100	0.369	160.6	4.238	75.3	0.119	65.3	0.171	-81.2
1200	0.373	155.7	3.897	73.2	0.128	65.1	0.168	-82.7
1300	0.377	151.2	3.616	71.0	0.137	65.1	0.167	-84.2
1400	0.382	146.9	3.369	68.8	0.147	64.5	0.167	-85.7
1500	0.384	142.1	3.154	66.8	0.156	64.1	0.168	-87.1
1600	0.386	138.7	2.960	64.5	0.166	63.5	0.168	-88.3
1700	0.391	133.7	2.803	62.9	0.175	63.0	0.169	-89.9
1800	0.401	130.6	2.662	60.6	0.185	62.4	0.171	-91.5
1900	0.405	127.4	2.533	59.1	0.193	61.7	0.172	-92.6
2000	0.408	12.8	2.416	57.0	0.202	61.1	0.175	-94.1





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